TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC4049AP,TC74HC4049AF,TC74HC4049AFN,TC74HC4049AFT TC74HC4050AP,TC74HC4050AF,TC74HC4050AFN,TC74HC4050AFT

TC74HC4049AP/AF/AFN/AFT H TC74HC4050AP/AF/AFN/AFT H

T Hex Buffer/Converter (inverting)

T Hex Buffer/Converter

The TC74HC4049A and TC74HC4050A are high speed CMOS HEX BUFFERs fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC4049A is an inverting buffer, while the TC74HC4050A is a non-inverting buffer. The internal circuits are composed of 3-stages (HC4049A) or 2-stages (HC4050A) of invertaers, which provided high noise immunity and stable output.

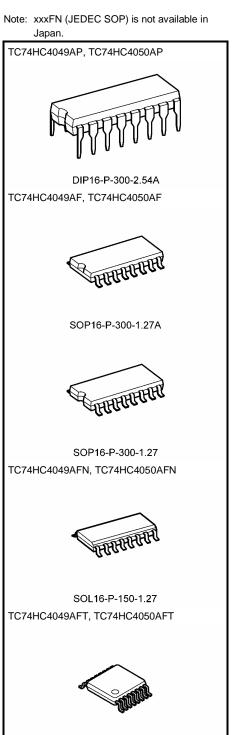
Input protection circuits are different from those of other high speed CMOS IC's. They eliminate the diodes on the V_{CC} side thus providing of logic-level conversion from high-level volages up to 15 V to low-level voltages.

They are useful for battery back up circuits, because input voltage can be applied on IC's which are not biased by V_{CC}.

Features

- High speed: $t_{pd} = 9 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 1 \ \mu A \ (max)$ at $Ta = 25^{\circ}C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Output Drive Capability: 15 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 6 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2 V to 6 V
- Pin and function compatible with 4049B/4050B

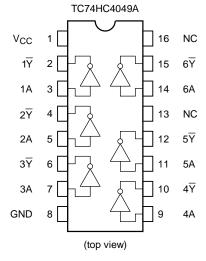
Weight	
DIP16-P-300-2.54A	: 1.00 g (typ.)
SOP16-P-300-1.27A	: 0.18 g (typ.)
SOP16-P-300-1.27	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.13 g (typ.)
TSSOP16-P-0044-0.65A	: 0.06 g (typ.)

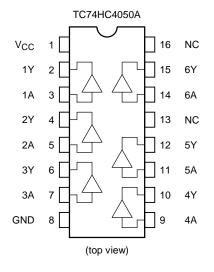


TSSOP16-P-0044-0.65A

<u>TOSHIBA</u>

Pin Assignment





NC: No connection

IEC Logic Symbol

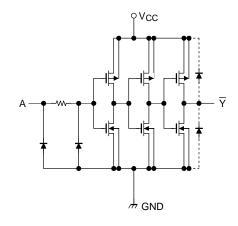
	TC74HC40	49A	
1A <u>(3)</u>	1	⊳	(<u>2)</u> 1 <u>Y</u>
2A <u>(5)</u>			<u>(4)</u> 2 <u></u> <u></u>
3A <u>(7)</u>			<u>(6)</u> 3 <u>7</u>
4A <u>(9)</u>			<u>(10)</u> 4 <u>Y</u>
5A <u>(11)</u>			<u>(12)</u> 5 <u></u> 7
6A <u>(14)</u>			(<u>15</u>) 6 <u>7</u>

Truth Table

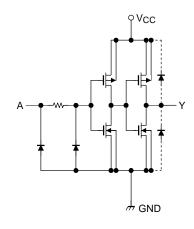
А	Y (4049A)	Y (4050A)
L	Н	L
Н	L	Н

Input and Output Equivalent Circuit

TC74HC4049A



TC74HC4050A



	TC74HC4050A	
1A <u>(3)</u>	1 ⊳	<u>(2)</u> 1Y
2A <u>(5)</u>		<u>(4)</u> 2Y
3A <u>(7)</u>		<u>(6)</u> 3Y
4A <u>(9)</u>		(<u>10)</u> 4Y
5A (11)		(<u>12)</u> 5Y
6A <u>(14)</u>		<u>(15)</u> 6Y

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7	V
DC input voltage	V _{IN}	-0.5 to 18 (Note 2)	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	lout	±35	mA
DC V _{CC} /ground current	ICC	±75	mA
Power dissipation	PD	500 (DIP) (Note 3)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: DC input voltage (V_{IN}) specified is measured to GND and is not related to V_{CC} .

Recommended operating range is 0 V to 15 V and it is possible to convert logic-levels from 15 V to 5 V or 5 V to 2 V.

Note 3: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2 to 6	V
Input voltage	V _{IN}	0 to 15	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
		0 to 1000 ($V_{CC} = 2.0 \text{ V}$)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol			-	Ta = 25°0)	-	ι = 0 85°C	Unit	
	-,			$V_{CC}(V)$	Min	Тур.	Max	Min	Max	
				2.0	1.50	_	_	1.50	_	
High-level input voltage	VIH	_		4.5	3.15		—	3.15	—	V
				6.0	4.20		_	4.20	_	
				2.0	_	_	0.50		0.50	
Low-level input voltage	VIL		—	4.5	—		1.35	—	1.35	V
Ŭ				6.0	_	—	1.80	—	1.80	
				2.0	1.9	2.0	_	1.9		
	V _{OH}	V _{IN} = VIH or VIL	$I_{OH}=-20~\mu A$	4.5	4.4	4.5	—	4.4	—	
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V
Ũ			$I_{OH} = -6 \text{ mA}$	4.5	4.18	4.31	—	4.13	—	
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
		V _{OL} V _{IN} = V _{IH} or V _{IL}		2.0	—	0.0	0.1		0.1	
			$I_{OL}=20~\mu A$	4.5	—	0.0	0.1	—	0.1	
Low-level output voltage	V _{OL}			6.0	_	0.0	0.1	—	0.1	V
-			$I_{OL} = 6 \text{ mA}$	4.5	—	0.17	0.26	—	0.33	
			$I_{OL} = 7.8 \text{ mA}$	6.0	_	0.18	0.26		0.33	
Input leakage	Input leakage		$V_{IN} = V_{CC}$ or GND		_		±0.1		±1.0	μA
current	I _{IN}	$V_{IN} = 15 V$		6.0		_	±0.5	_	±5.0	μΛ
Quiescent supply current	ICC	$V_{IN} = V_{CC}$ or GND		6.0		_	1.0	_	10.0	μΑ

AC Characteristics (input: $t_r = t_f = 6 \text{ ns}$)

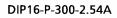
Characteristics Symbol		Test Condition			Ta = 25°C			Ta = –40 to 85°C		Unit		
			C _L (pF)	V _{CC} (V)	Min	Тур.	Max	Min	Max			
	t			2.0		25	60	_	75			
Output transition time	t _{TLH}	—	50	4.5	_	6	12	_	15	ns		
	t _{THL}			6.0	—	5	10	—	13			
time					2.0	_	30	75	_	95		
	t _{pLH}		50	4.5	_	9	15	_	19			
		t _{pLH}	t _{pLH}	t _{pLH}			6.0	—	8	13	—	16
	t _{pHL}	t _{pHL}		2.0	_	45	100	_	145	115		
			150	150	4.5	_	14	20	_	29		
				6.0	—	12	17	—	25			
Input capacitance	C _{IN}		_		_	5	10	_	10	pF		
Power dissipation capacitance	C _{PD}			(Note)	_	26	_	_	_	pF		

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

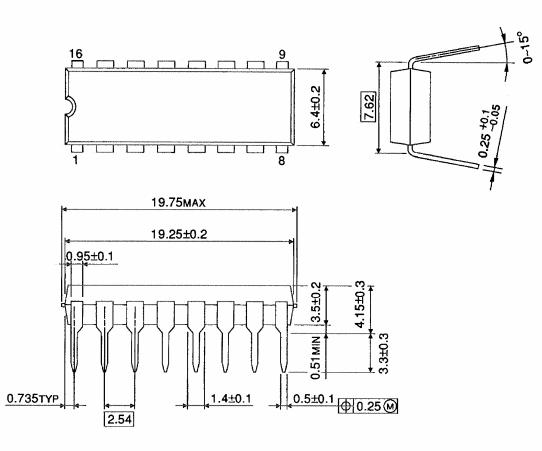
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per gate)

Package Dimensions



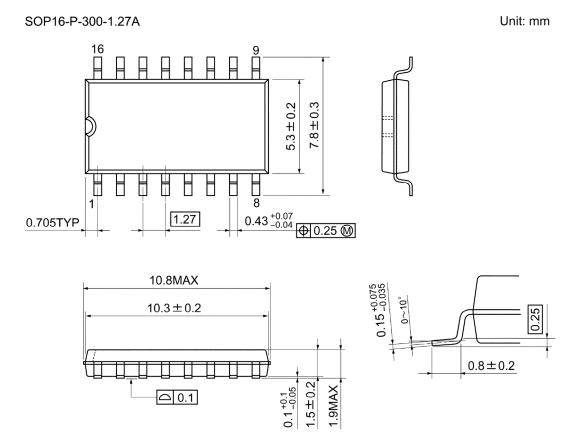
Unit : mm



Weight: 1.00 g (typ.)

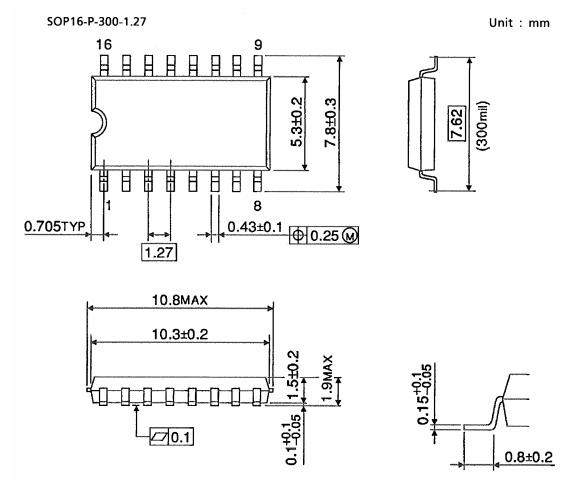
TOSHIBA

Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions

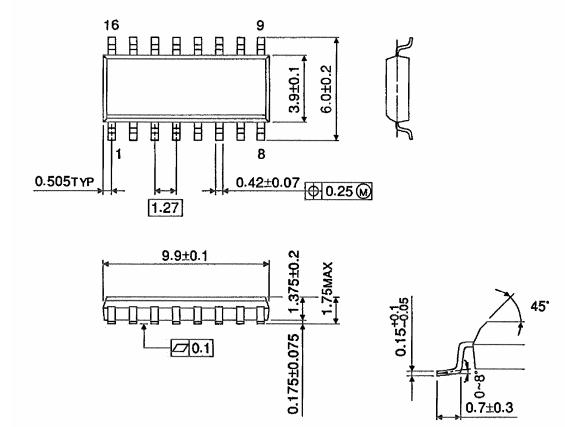


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27

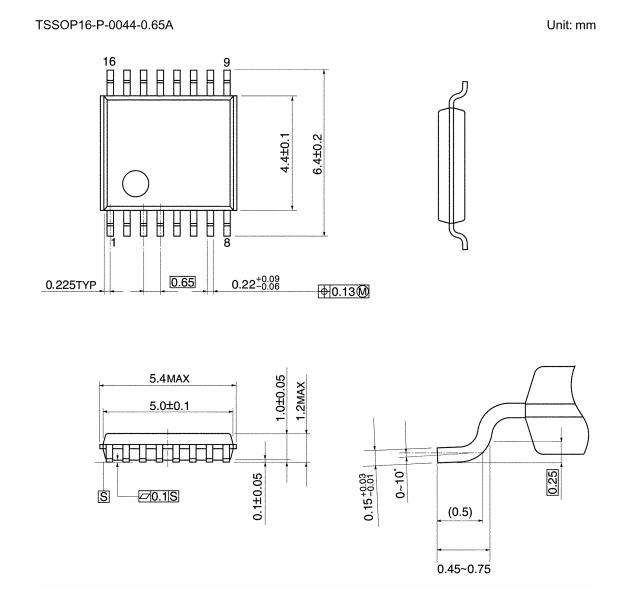
Unit : mm



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

Package Dimensions



Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

DIP16-P-300-2.54A SOP16-P-300-1.27A SOL16-P-150-1.27 TSSOP16-P-0044-0.65A

RESTRICTIONS ON PRODUCT USE

Handbook" etc. 021023_A

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